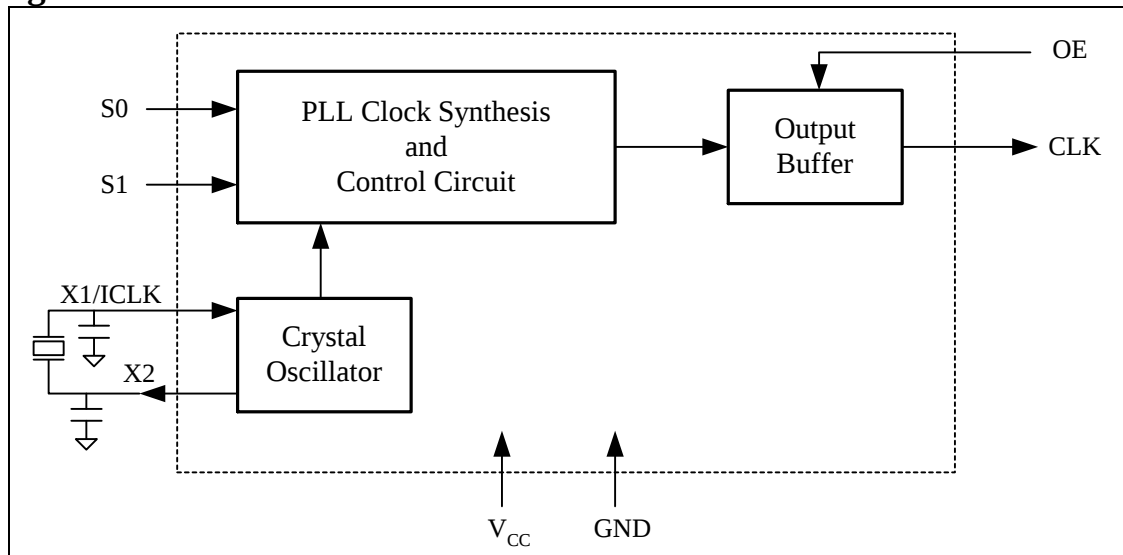


Block Diagram



External Components

Decoupling Capacitor

As with any high-performance mixed-signal IC, the PT7C4511 must be isolated from system power supply noise to perform optimally. A decoupling capacitor of 0.01 μ F or 0.1 μ F must be connected between VCC and the GND. It must be connected close to the PT7C4511 to minimize lead inductance. No external power supply filtering is required for the PT7C4511.

Series Termination Resistor

A 33 Ω terminating resistor can be used next to the CLK pin for trace lengths over one inch.

Crystal Load Capacitors

There is no on-chip capacitance build-in chip. A parallel resonant, fundamental mode crystal should be used. The device crystal connections should include

pads for small capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load capacitance. Because load capacitance can only be increased in this trimming process, it is important to keep stray capacitance to a minimum by using very short PCB traces (and no vias) between the crystal and device. Crystal capacitors, if needed, must be connected from each of the pins X1 and X2 to ground. The value (in pF) of these crystal caps should equal $C_L \times 2$. In this equation, C_L = crystal load capacitance in pF. Example: For a crystal with a 15 pF load capacitance, each crystal capacitor would be 30pF.

Maximum Ratings

Storage Temperature.....	-65°C to +150°C
Ambient Operating Temperature.....	-40°C to +85°C
Supply Voltage to Ground Potential (V _{CC}).....	-0.3V to +7.0V
Inputs(Referenced to GND).....	-0.5V to V _{CC} +0.5V
Clock Output(Referenced to GND).....	-0.5V to V _{CC} +0.5V

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Sym	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	Supply voltage	-	3.0	-	5.5	V
T _A	Operating temperature	-	-40	-	+85	°C

DC Electrical Characteristics

($V_{CC} = 3.3V \pm 0.3V$, $T_A = -40 \sim 85^\circ C$, unless otherwise noted)

Sym.	Parameter	Test Condition	Pin	Min.	Typ.	Max.	Unit
V _{CC}	Supply Voltage	-	V _{CC}	3	3.3	3.6	V
I _{CC}	Supply Current	no load, 20MHz crystal, 100MHz output	V _{CC}	-	12	20	mA
V _{IH}	Input Logic High	-	ICLK	(V _{CC} /2)+1	V _{CC} /2	-	V
			OE	2	-	-	V
V _{IL}	Input Logic Low	-	ICLK	-	V _{CC} /2	(V _{CC} /2)-1	V
			OE	-	-	0.8	V
V _{IH}	Input Logic High	-	S0, S1	V _{CC} -0.5	-	-	V
V _{IM}	Input mid-level	-	S0, S1	-	V _{CC} /2	-	V
V _{IL}	Input Logic Low	-	S0, S1	-	-	0.5	V
V _{OH}	High-level output voltage	I _{OH} = -12mA	CLK	2.4	-	-	V
V _{OL}	Low-level output voltage	I _{OL} = 12mA	CLK	-	-	0.4	V
R	Internal pull up resistance	-	OE	-	270	-	kΩ
I _S	Short Circuit Current	-	CLK	-	±30	-	mA

($V_{CC} = 5.0V \pm 0.5V$, $T_A = -40 \sim 85^\circ C$, unless otherwise noted)

Sym.	Parameter	Test Condition	Pin	Min.	Typ.	Max.	Unit
V _{CC}	Supply Voltage	-	V _{CC}	4.5	5.0	5.5	V
I _{CC}	Supply Current	no load, 20MHz crystal, 100MHz output	V _{CC}	-	20	30	mA
V _{IH}	Input Logic High	-	ICLK	(V _{CC} /2)+1	V _{CC} /2	-	V
			OE	0.65*V _{CC}	-	-	V
V _{IL}	Input Logic Low	-	ICLK	-	V _{CC} /2	(V _{CC} /2)-1	V
			OE	-	-	0.8	V
V _{IH}	Input Logic High	-	S0, S1	V _{CC} -0.4	-	-	V
V _{IM}	Input mid-level	-	S0, S1	-	V _{CC} /2	-	V
V _{IL}	Input Logic Low	-	S0, S1	-	-	0.4	V
V _{OH}	High-level output voltage	I _{OH} = -12mA	CLK	V _{CC} -0.5	-	-	V
V _{OL}	Low-level output voltage	I _{OL} = 12mA	CLK	-	-	0.4	V
R	Internal pull up resistance	-	OE	-	270	-	kΩ
I _S	Short Circuit Current	-	CLK	-	±70	-	mA

AC Electrical Characteristics

($V_{CC} = 3.3V \pm 0.3V$, $T_A = -40 \sim 85^\circ C$, unless otherwise noted)

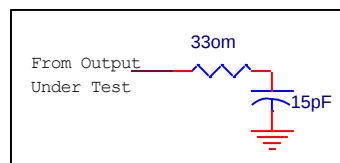
Sym.	Parameter	Test Condition	Pin	Min.	Typ.	Max.	Unit
f_{IN}	Input Frequency	-	ICLK	1	-	50	MHz
f_{OUT}	Output Frequency	V_{CC} : 3.0 to 3.6V	CLK	20	-	180	MHz
t_R	Output clock rise time	0.8 to 2.0V, 15pF load	CLK	-	1	-	ns
t_F	Output clock fall time	2.0 to 0.8V, 15pF load	CLK	-	1	-	ns
Duty	Output clock duty cycle	At $V_{CC}/2$, below 160MHz	CLK	45	50	55	%
		At $V_{CC}/2$, 160MHz to 180MHz	CLK	40	-	60	%
	PLL bandwidth	-	-	10	-	-	kHz
	Output enable time	OE high to output on	-	-	-	50	ns
	Output disable time	OE low to tri-rise	-	-	-	50	ns
	Period Jitter	70MHz~180MHz	CLK	-	50	100	ps
	Jitter over 200ns interval	100MHz~180MHz	CLK	-	-	200	ps

($V_{CC} = 5.0V \pm 0.5V$, $T_A = -40 \sim 85^\circ C$, unless otherwise noted)

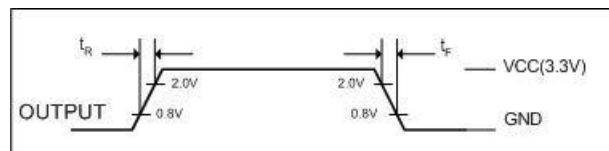
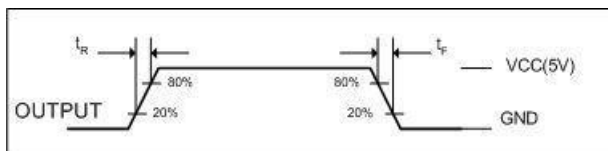
Sym.	Parameter	Test Condition	Pin	Min.	Typ.	Max.	Unit
f_{IN}	Input Frequency	-	ICLK	1	-	50	MHz
f_{OUT}	Output Frequency	V_{CC} : 4.5 to 5.5V	CLK	20	-	200	MHz
t_R	Output clock rise time	20% V_{CC} to 80% V_{CC} , 15pF load	CLK	-	1.2	-	ns
t_F	Output clock fall time	80% V_{CC} to 20% V_{CC} , 15pF load	CLK	-	1.2	-	ns
Duty	Output clock duty cycle	At $V_{CC}/2$, below 160MHz	CLK	45	50	55	%
		At $V_{CC}/2$, 160MHz to 200MHz	CLK	40	-	60	%
	PLL bandwidth	-	-	10	-	-	kHz
	Output enable time	OE high to output on	-	-	-	50	ns
	Output disable time	OE low to tri-rise	-	-	-	50	ns
	Period Jitter	70MHz~200MHz	CLK	-	50	100	ps
	Jitter over 200ns interval	100MHz~200MHz	CLK	-	-	200	ps

Test circuits

1>Load circuit for output clock duty cycle, rise and fall time Measurement

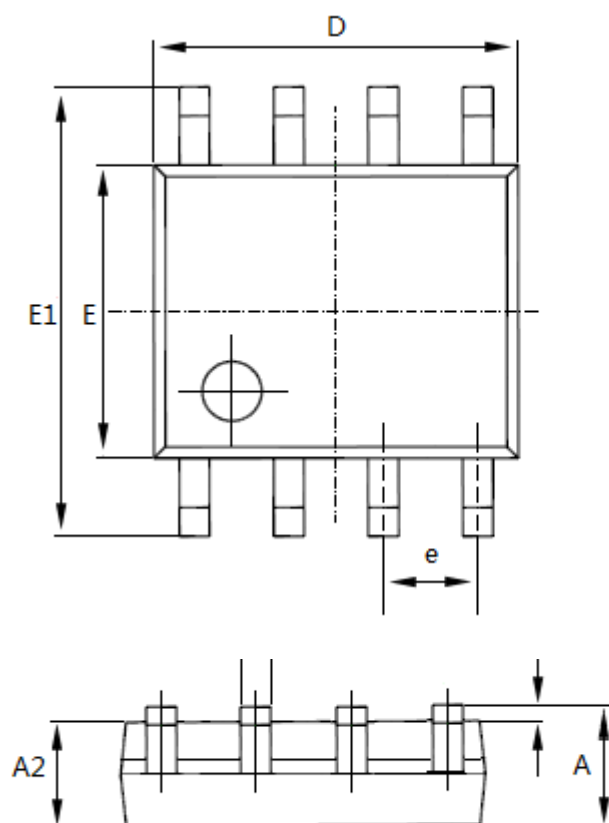


2>Timing Definitions for output clock rise and fall time Measurement



Mechanical Information

SOIC-8



Note:

- 1) Controlling dimensions in millimeters.
- 2) Ref: JEDEC MS-012E/AA

Symbol	Dimensions In Millimeters	
	Min	Max
A	1.350	1.750
A1	0.100	0.250
A2	1.350	1.550
b	0.330	0.510
c	0.170	0.250
D	4.700	5.100
E	3.800	4.000
E1	5.800	6.200
e	1.27 BSC	
L	0.400	1.270
θ	0°	8°

Ordering Information

Part No.	Package Code	Package
PT7C4511WE	W	Lead free and Green 8-pin SOIC

Pericom Semiconductor Corporation • 1-800-435-2336 • www.pericom.com

Pericom reserves the right to make changes to its products or specifications at any time, without notice, in order to improve design or performance and to supply the best possible product. Pericom does not assume any responsibility for use of any circuitry described other than the circuitry embodied in Pericom product. The company makes no representations that circuitry described herein is free from patent infringement or other rights, of Pericom.